TOSHIBA TRANSISTOR SILICON NPN TRIPLE DIFFUSED MESA TYPE

2SD2500

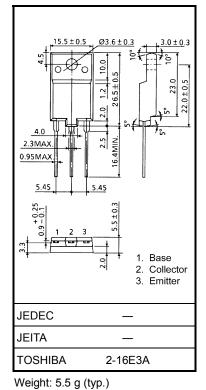
HORIZONTAL DEFLECTION OUTPUT FOR COLOR TVs

Unit: mm

- High Voltage : V_{CBO} = 1500 V
- Low Saturation Voltage : VCE (sat) = 3 V (Max.)
- High Speed : $t_f = 0.35 \mu s$ (Typ.)
- Collector Metal (Fin) is Fully Covered with Mold Resin.

CHARACTERISTIC		SYMBOL	RATING	UNIT	
Collector-Base Voltage		V _{CBO}	1500	V	
Collector-Emitter Voltage		V _{CEO}	600	V	
Emitter-Base Voltage		V _{EBO}	5	V	
Collector Current	DC	Ι _C	10	A	
	Pulse	I _{CP}	20		
Base-Current		Ι _Β	5	А	
Collector Power Dissipation		P _C	50	W	
Junction Temperature		Тј	150	°C	
Storage Temperature Range		T _{stg}	-55~150	°C	

ABSOLUTE MAXIMUM RATINGS (Tc = 25°C)



Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in

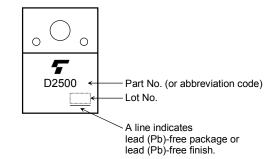
temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

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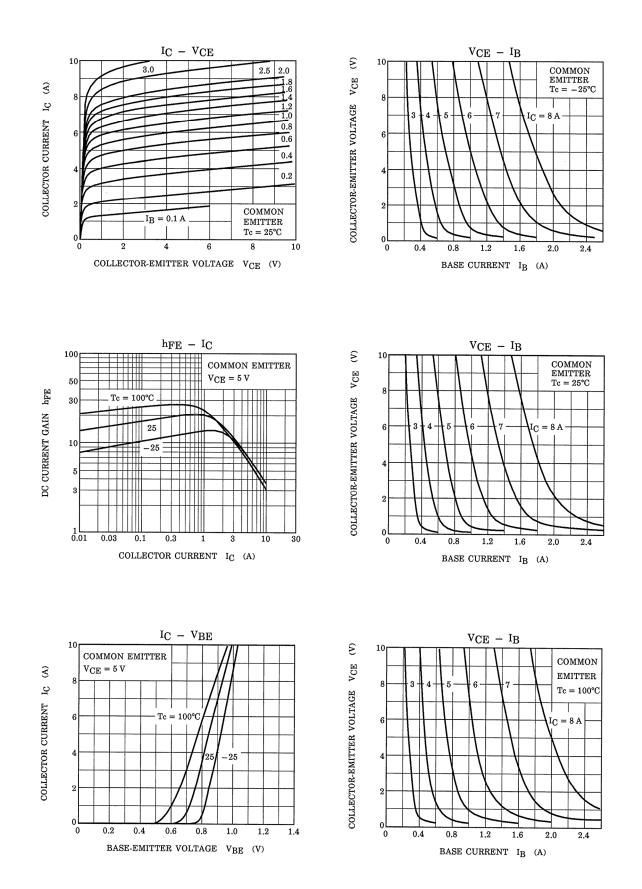
ELECTRICAL CHARACTERISTICS (Tc = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Collector Cut-off Current		I _{CBO}	V _{CB} = 1500 V, I _E = 0	_	_	1	mA
Emitter Cut-off Current		I _{EBO}	V _{EB} = 5 V, I _C = 0	-	-	10	μA
Collector-Emitter Breakdown Voltage		V (BR) CEO	I _C = 10 mA, I _B = 0	600	_	—	V
DC Current Gain		h _{FE (1)}	V _{CE} = 5 V, I _C = 1 A	10		30	_
		h _{FE (2)}	V _{CE} = 5 V, I _C = 6	4	_	8	
Collector-Emitter Saturation Voltage		V _{CE (sat)}	I _C = 6A I _B = 1.5A	_	_	3	V
Base-Emitter Saturation Voltage		V _{BE (sat)}	I _C = 6A I _B = 1.5A	-	1.0	1.4	V
Transition Frequency		f _T	V _{CE} = 10 V, I _C = 0.1 A	-	1.7	—	MHz
Collector Output Capacitance		C _{ob}	V _{CB} = 10 V, I _E = 0, f = 1 MHz	-	135	—	pF
Switching Time	Storage Time	t _{stg}	I _{CP} = 6A, I _{B1} (end) = 1.5A f _H = 15.75kHz	-	7	11	μs
	Fall Time	t _f		_	0.35	0.7	

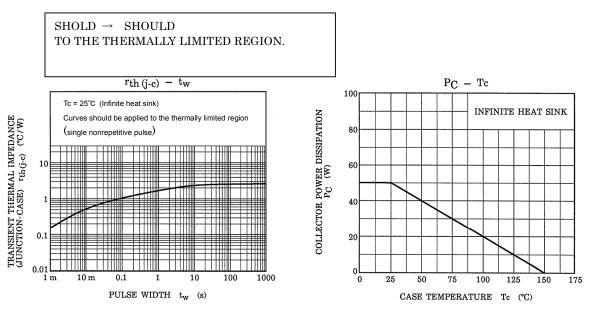
MARKING

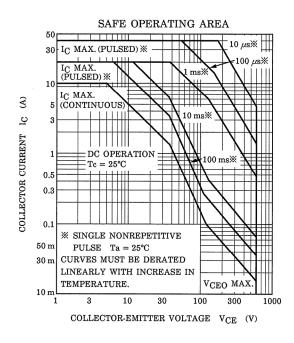


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